CLAIMS

What is claimed is:

1. A method comprising:

selecting a dicing tape with an adhesive layer that has a thickness greater than a height of one or more bump electrodes of a wafer; and

applying the dicing tape to the wafer such that the adhesive layer conforms to the one or more bump electrodes.

- 2. The method of claim 1 wherein the wafer is a double bumped wafer.
- 3. The method of claim 2 wherein the dicing tape is applied using a mounting pressure roller wherein the adhesive layer helps to distribute a pressure applied by the mounting pressure roller.
- 4. The method of claim 3 wherein the dicing tape is a radiation sensitive tape.
- 5. The method of claim 4 wherein the bump electrodes have a height of approximately 60 microns and the adhesive layer has a thickness of approximately 130 microns.
- 6. The method of claim 5 further comprising: mounting the wafer on a support member; and dicing the wafer using a dual-blade dicing process.

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- 7. The method of claim 6 further comprising:
- irradiating a backside of the dicing tape to reduce an adhesive strength of the adhesive

layer.

8. The method of claim 7 wherein the adhesive strength is reduced from a pre-radiation

adhesive strength of approximately 200 grams/25 mm² to a post-radiation adhesive strength of

approximately 2 grams/25 mm².

9 An assembly comprising:

a wafer having bump electrodes formed on at least one of two opposing surfaces; and

a dicing tape applied to one of the at least one surfaces, the dicing tape having an

adhesive layer that is thicker than a height of the bump electrodes such that the adhesive layer

conforms to the bump electrodes.

10. The assembly of claim 9 wherein the dicing tape is applied using a mounting pressure

roller wherein the adhesive layer helps to distribute a pressure applied by the mounting pressure

roller.

11. The assembly of claim 10 wherein the dicing tape is a radiation sensitive tape.

- 12. The assembly of claim 11 wherein the bump electrodes have a height of approximately 60 microns and the adhesive layer has a thickness of approximately 130 microns.
- 13. The assembly of claim 12 wherein an adhesive strength of the dicing tape is reduced from a pre-radiation adhesive strength of approximately 200 grams/25 mm² to a post-radiation adhesive strength of approximately 2 grams/25 mm².
- 14. A method comprising:

determining a height of one or more bump electrodes on a wafer surface; and selecting a dicing tape based upon the determined height of the one or more bump electrodes.

- 15. The method of claim 14 wherein the wafer is a double bumped wafer.
- 16. The method of claim 15 wherein selecting the dicing tape based upon the determined height of the one or more bump electrodes includes selecting a dicing tape having an adhesive layer thicker than the determined height of the one or more bump electrodes
- 17. The method of claim 16 further comprising:

applying the dicing tape to the wafer such that the adhesive layer conforms to the one or more bump electrodes.

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- 18. The method of claim 17 wherein the dicing tape is applied using a mounting pressure roller wherein the adhesive layer helps to distribute a pressure applied by the mounting pressure roller.
- 19. The method of claim 14 wherein the dicing tape is a radiation sensitive tape having a preradiation adhesive strength of approximately 200 grams/25 mm², and a post-radiation adhesive strength of approximately 2 grams/25 mm².
- 20. The method of claim 14 wherein the bump electrodes have a height of approximately 60 microns and the adhesive layer has a thickness of approximately 130 microns.
- 21. The method of claim 20 further comprising:
 mounting the wafer on a support member; and
 dicing the wafer using a dual-blade dicing process.
- 22. The method of claim 21 further comprising:
 irradiating a backside of the dicing tape to reduce an adhesive strength of the adhesive layer.
- 23. A method comprising:

applying an adhesive to a wafer surface, the wafer surface having one or more bump electrodes formed thereon, the adhesive covering the one or more bump electrodes to form an adhesive layer; and

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042390.P17764 Express Mail Label No.: EV409365446US applying a backing film to the adhesive layer.

24. The method of claim 23 wherein the wafer is a double bumped wafer.

25. The method of claim 23 wherein the backing film is applied using a mounting pressure

roller wherein the adhesive layer helps to distribute a pressure applied by the mounting pressure

roller.

26. The method of claim 25 wherein the bump electrodes have a height of approximately 60

microns and the adhesive layer has a thickness of approximately 130 microns.

27. The method of claim 23 further comprising:

mounting the wafer on a support member; and

dicing the wafer using a dual-blade dicing process.

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